

100Gb/s QSFP28 CWDM4 1310nm 2km Optical Transceiver

Features

- QSFP28 MSA compliant
- 4 CWDM lanes MUX/DEMUX design
- Supports 103.1Gb/s aggregate bit rate
- 100G CWDM4 MSA Technical Spec Rev1.1
- Up to 2km transmission on single mode fiber (SMF) with FEC
- Operating case temperature:0 to 70℃
- 4x25G electrical interface (OIF CEI-28GVSR)
- Maximum power consumption 3.5W
- LC duplex connector
- RoHS compliant

Applications

- 100G Ethernet
- Data Center Interconnect
- Enterprise networking

Compliance

- Compliant with IEEE 802.3ae-2002
- Compliant with MSA SFF-8636



Description

This product is a transceiver module designed for 2km optical communication applications. The design is compliant to 1000GBASE CWDM4 MSA standard. The module converts 4 inputs channels (ch) of 25Gb/s electrical data to 4 CWDM optical signals, and multiplexes them into a single channel for 100Gb/s optical transmission. Reversely, on the receiver side, the module optically de-multiplexes a 100Gb/s input into 4 CWDM channels signals, and converts them to 4 channel output electrical data.

The central wavelengths of the 4 CWDM channels are 1271, 1291, 1311 and 1331nm as members of the CWDM wavelength grid defined in ITU-T G.694.2. It contains a duplex LC connector for the optical interface and a 38-pin connector for the electrical interface. To minimize the optical dispersion in the long-haul system, single-mode fiber (SMF) has to be applied in this module. Host FEC is required to support up to 2km fiber transmission.

The product is designed with form factor, optical/electrical connection and digital diagnostic interface according to the QSFP28 Multi-Source Agreement (MSA). It has been designed to meet the harshest external operating conditions including temperature, humidity and EMI interference.

Absolute Maximum Ratings

| Table1-Absolute Maximum Ratings | | | | | | | |
|---------------------------------|---------|------|---------|------|------|-------|--|
| Parameter | Symbols | Min. | Typical | Max. | Unit | Notes | |
| Storage Temperature | Ts | -40 | | +85 | °C | | |
| Operating Case Temperature | Тс | 0 | | +70 | % | | |
| Supply Voltage | VCC | -5 | | 3.6 | V | | |
| Damage Threshold,each Lane | THd | 3.5 | | | dBm | | |

Recommended Operating Conditions

| Table2-Recommended Operating Conditions | | | | | | | |
|-----------------------------------------|---------|-------|----------|-------|------|-------|--|
| Parameter | Symbols | Min. | Typical | Max. | Unit | Notes | |
| Operating Case Temperature | Тор | 0 | 25 | +70 | °C | | |
| Power Supply Voltage | Vcc | 3.135 | 3.3 | 3.465 | V | | |
| Power Supply Current | Icc | | | 300 | mA | | |
| Data Rate, each Lane | | | 25.78125 | | Gb/s | | |



Electrical Characteristic

| Table3-Electric | al Characteris | stic | | | | _ | |
|----------------------------------------------------------|----------------|--------|--------------------|------------------------------------|--------|------|------------------|
| Parameter | | Symbol | Min. | Typical | Max. | Unit | Notes |
| | | 0 | ptical Transr | nitter Characteristi | ics | | |
| Bit Rate per Lane | | | 25.78125 ± 100 ppm | | | Gbps | |
| | CH0 | λ c1 | 1264.5 | 1271 | 1277.5 | nm | |
| Center | CH1 | λ c2 | 1284.5 | 1291 | 1297.5 | nm | |
| Wavelength | CH2 | λсЗ | 1304.5 | 1311 | 1317.5 | nm | 1 |
| | CH3 | λ c4 | 1324.5 | 1331 | 1337.5 | nm | At 1MHz |
| Overload Differential Voltage pk-pk | | TP1a | 900 | | | mV | |
| Average Launch Power per Lane | | Peach | -6.5 | | 2.5 | dBm | |
| Optical modulation amplitude per lane | | POMA | -4 | | 2.5 | dBm | 1 |
| Transmitter Eye Mask Definition {X1, X2, X3, Y1, Y2, Y3} | | | | {0.31, 0.4, 0.45, 0.34, 0.38, 0.4} | | | |
| Total Average Launch Power | | PT | | | 8.5 | dBm | |
| Extinction Ratio | | | | 3.5 | | dB | |
| | | | Optical Rece | iver Characteristic | S | | |
| Damage Thresh | old, each Lane | THd | 3.5 | | | dBm | 2 |
| Total Average Receive Power | | | | | 8.5 | dBm | |
| Average Receive Power each Lane | | | -11.5 | | 2.5 | dBm | |
| Receiver Sensitivity (OMA), each Lane | | Rsen | | | -10 | dBm | for BER = 5x10-5 |
| LOS Hysteresis | | LOSH | 0.5 | | | dB | |
| LOS Assert | | LOSA | -30 | | | dBm | |
| LOS Deassert | | LOSD | | | -12 | dBm | |

Notes:

[1]Even if the TDP $\,<\,$ 1.0 dB, the OMA min must exceed the minimum value specified here.

[2] The receiver shall be able to tolerate, without damage, continuous exposure to a modulated optical input signal having this power level on one lane. The receiver does not have to operate correctly at this input power.



Digital diagnostic specification table

Table4- Digital diagnostic specification table

| Parameter | Symbols | Min. | Max. | Unit | Notes |
|------------------------------------------------|-----------|------|------|------|---------------------------|
| Internally measured transceiver temperature | DMI_Temp | -3 | 3 | °C | Over operating temp |
| Measured RX received average optical power | DMI_TX | -2 | 2 | dB | |
| Measured TX output power | DMI_RX | -2 | 2 | dB | -1dBm to -16dBm range |
| Internally measured transceiver supply voltage | DMI_VCC | -100 | 100 | mV | Full operating range |
| Measured TX bias current | DMI_Ibias | -10 | 10 | % | |

Pin Description

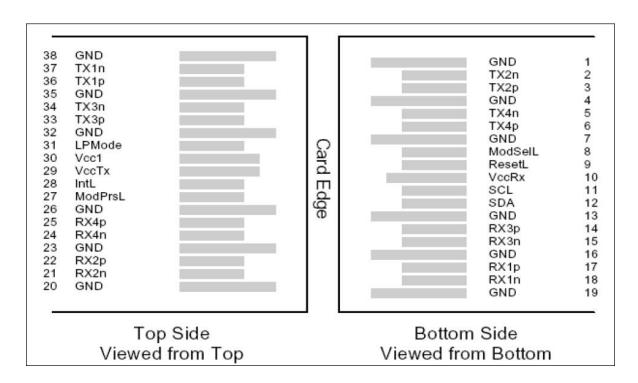


Figure 1 Pin view



Pin Function Definitions

| in | Symbols | Description | Notes |
|----|---------|-------------------------------------|-------|
| 1 | GND | Ground | 1 |
| 2 | Tx2n | Transmitter Inverted Data Input | |
| 3 | Tx2p | Transmitter Non-Inverted Data Input | |
| 4 | GND | Ground | 1 |
| 5 | Tx4n | Transmitter Inverted Data Input | |
| 6 | Tx4p | Transmitter Non-Inverted Data Input | |
| 7 | GND | Ground | |
| 8 | ModSelL | Module Select | |
| 9 | ResetL | Module Reset | |
| 10 | Vcc Rx | +3.3V Power Supply Receiver | 2 |
| 11 | SCL | 2-wire serial interface clock | |
| 12 | SDA | 2-wire serial interface data | |
| 13 | GND | Ground | |
| 14 | Rx3p | Receiver Non-Inverted Data Output | |
| 15 | Rx3n | Receiver Inverted Data Output | |
| 16 | GND | Ground | 1 |
| 17 | Rx1p | Receiver Non-Inverted Data Output | |
| 18 | Rx1n | Receiver Inverted Data Output | 1 |
| 19 | GND | Ground | 1 |
| 20 | GND | Ground | |
| 21 | Rx2n | Receiver Inverted Data Output | |
| 22 | Rx2p | Receiver Non-Inverted Data Output | |
| 23 | GND | Ground | |
| 24 | Rx4n | Receiver Inverted Data Output | |
| 25 | Rx4p | Receiver Non-Inverted Data Output | |
| 26 | GND | Ground | 1 |
| 27 | ModPrsL | Module Present | |
| 28 | IntL | Interrupt | |
| 29 | VccTx | +3.3V Power supply transmitter | 2 |
| 30 | Vcc1 | +3.3V Power supply | 2 |
| 31 | LPMode | Low Power Mode | |
| 32 | GND | Ground | 1 |
| 33 | Тх3р | Transmitter Non-Inverted Data Input | |
| 34 | Tx3n | Transmitter Inverted Data Input | |
| 35 | GND | Ground | 1 |
| 36 | Tx1p | Transmitter Non-Inverted Data Input | |



| 37 | Tx1n | Transmitter Inverted Data Input | |
|----|------|---------------------------------|---|
| 38 | GND | Ground | 1 |

Notes:

- [1] GND is the symbol for signal and supply (power) common for the module. All are common within the module and all module voltages are referenced to this potential unless otherwise noted. Connect these directly to the host board signal-common ground plane.
- [2] Vcc Rx, Vcc1 and Vcc Tx are the receiver and transmitter power supplies and shall be applied concurrently. Recommended host board power supply filtering is shown in Figure 2. Vcc Rx Vcc1 and Vcc Tx may be internally connected within the Module in any combination. The connector pins are each rated for a maximum current of 1000 mA.



Monitoring Specification

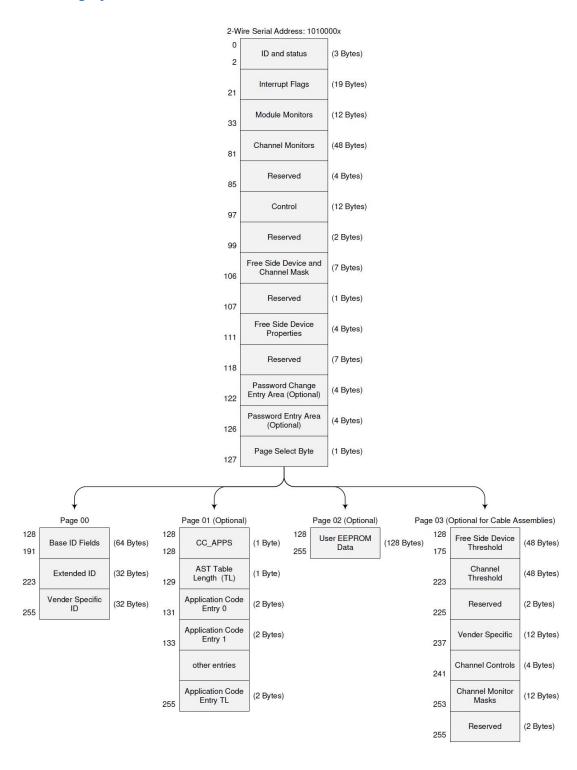


Figure 2 Memory Map



Transceiver Block Diagram

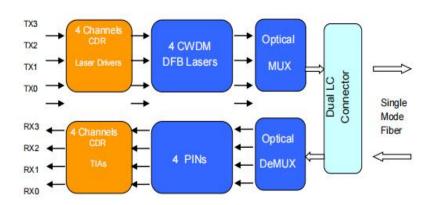


Figure 3 Transceiver Block Diagram

Mechanical Dimensions

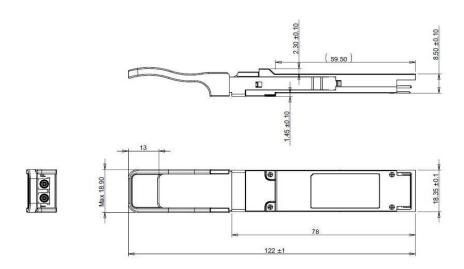


Figure 4 Mechanical Outline

ESD

This transceiver is specified as ESD threshold 1kV for high speed data pins and 2kV for all other electrical input pins, tested per MIL-STD-883, Method 3015.4 /JESD22-A114-A (HBM). However, normal ESD precautions are still required during the handling of this module. This transceiver is shipped in ESD protective packaging. It should be removed from the packaging and handled only in an ESD protected environment.

Laser Safety

This is a Class 1 Laser Product according to EN 60825-1:2014. This product complies with 21 CFR 1040.10 and 1040.11 except for deviations pursuant to Laser Notice No. 50, dated (June 24, 2007).

Caution: Use of controls or adjustments or performance of procedures other than those specified herein may result in hazardous radiation exposure.



Further Information:

Web www.naddod.com

Email For order requirements: sales@naddod.com For cooperation: agency@naddod.com

For customer service: support@naddod.com For other informations: info@naddod.com

For technical support: tech@naddod.com

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